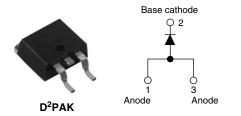


Vishay High Power Products

Input Rectifier Diode, 10 A



PRODUCT SUMMARY					
V _F at 10 A	< 1 V				
I _{FSM}	200 A				
V _{RRM}	800/1200 V				

DESCRIPTION/FEATURES

The 10ETS..S rectifier series has been optimized for very low forward voltage drop, with moderate leakage. The glass passivation technology used has reliable operation up to 150 °C junction temperature.

Typical applications are in input rectification and these products are designed to be used with Vishay HPP switches and output rectifiers which are available in identical package outlines.

This product series has been designed and qualified for industrial level.

OUTPUT CURRENT IN TYPICAL APPLICATIONS							
APPLICATIONS	SINGLE-PHASE BRIDGE	THREE-PHASE BRIDGE	UNITS				
Capacitive input filter $T_A = 55 \text{ °C}$, $T_J = 125 \text{ °C}$ common heatsink of 1 °C/W	12.0	16.0	A				

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	CHARACTERISTICS VALUES UN					
I _{F(AV)}	Sinusoidal waveform	10	А				
V _{RRM}		800/1200	V				
I _{FSM}		200	A				
V _F	10 A, T _J = 25 °C	1.1	V				
TJ		- 40 to 150	°C				

VOLTAGE RATINGS							
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA				
10ETS08S	800	900					
10ETS10S	1000	1100	0.5				
10ETS12S	1200	1300					

ABSOLUTE MAXIMUM RATII	NGS			
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current	I _{F(AV)}	$T_C = 105 \ ^{\circ}C$, 180° conduction half sine wave	10	
Maximum peak one cycle		10 ms sine pulse, rated V_{RRM} applied	170	A
non-repetitive surge current	IFSM	10 ms sine pulse, no voltage reapplied	200	
Maximum I ² t for fusing	l ² t	10 ms sine pulse, rated V_{RRM} applied		A ² s
Maximum I-t for fusing	1-1	10 ms sine pulse, no voltage reapplied	145	A-S
Maximum I ² √t for fusing	l²√t	t = 0.1 to 10 ms, no voltage reapplied	1450	A²√s

10ETS..S High Voltage Series

Vishay High Power Products Input Rectifier Diode, 10 A



ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum forward voltage drop	V _{FM}	10 A, T _J = 25 °C		1.1	V	
Forward slope resistance	r _t	T.I = 150 °C	20	mΩ		
Threshold voltage	V _{F(TO)}	1j=150 C	0.82	V		
		$T_J = 25 ^{\circ}C$		0.05	mA	
Maximum reverse leakage current	IRM	T _J = 150 °C	V _R = Rated V _{RRM}	0.50	IIIA	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction and storage temperature range	T _J , T _{Stg}		- 40 to 150	°C		
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	2.5	°C/W		
Maximum thermal resistance, junction to ambient (PCB mount)	R _{thJA} ⁽¹⁾		62	0/11		
Soldering temperature	Τs		240	°C		
Approximate weight			2	g		
			0.07	oz.		
			10ETS08S			
Marking device		Case style D ² PAK (SMD-220)	10ETS10S			
			10ETS12S			

Note

⁽¹⁾ When mounted on 1" square (650 mm²) PCB of FR-4 or G-10 material 4 oz. (140 μm) copper 40 °C/W For recommended footprint and soldering techniques refer to application note #AN-994



10ETS..S High Voltage Series

Input Rectifier Diode, 10 A Vishay High Power Products

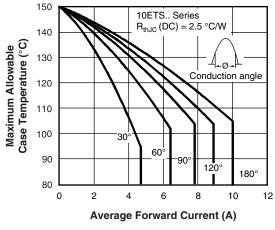


Fig. 1 - Current Rating Characteristics

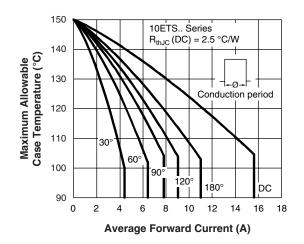
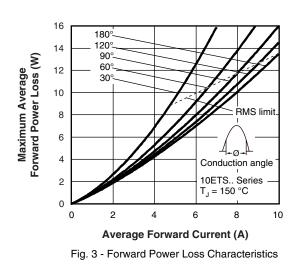


Fig. 2 - Current Rating Characteristics



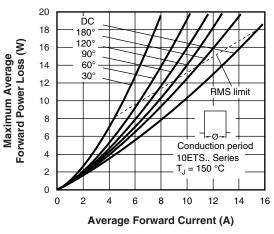


Fig. 4 - Forward Power Loss Characteristics

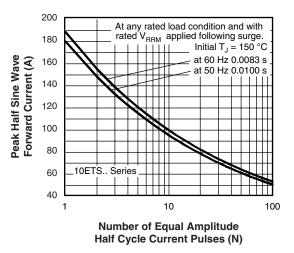


Fig. 5 - Maximum Non-Repetitive Surge Current

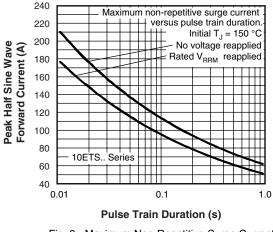


Fig. 6 - Maximum Non-Repetitive Surge Current

10ETS..S High Voltage Series

Vishay High Power Products Input Rectifier Diode, 10 A



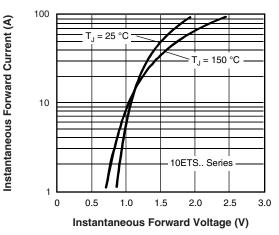


Fig. 7 - Forward Voltage Drop Characteristics

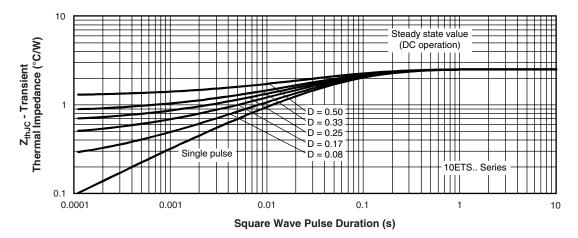


Fig. 8 - Thermal Impedance ZthJC Characteristics



Input Rectifier Diode, 10 A Vishay High Power Products

ORDERING INFORMATION TABLE

Device code	10	E	т	s	12	S	TRL	-
	1	2	3	4	5	6	7	8
	1	- Circ	uit confi	ng (10 = iguratior tiode	-			
	3	- Pac	E = Single diode Package T = TO-220AC					
	4		e of silic Standaı	con rd recov	ery recti	ifier	Г	08 = 80
	5 6			le x 100) D ² PAK		-	rsion	10 = 100 12 = 120
	7	• TF		ube pe and r pe and ı	,		,	
	8	- • N	one = St	tandard ad (Pb)-1	product			

LINKS TO RELATED DOCUMENTS					
Dimensions http://www.vishay.com/doc?95046					
Part marking information	http://www.vishay.com/doc?95054				
Packaging information	http://www.vishay.com/doc?95032				



Vishay

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>>Vishay(威世)